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July 2014

# FDMA1023PZ

# **Dual P-Channel PowerTrench® MOSFET**

-20V, -3.7A, 72mΩ

#### **Features**

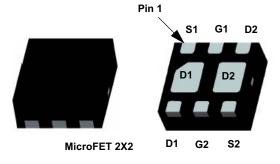
- Max  $r_{DS(on)}$  = 72m $\Omega$  at  $V_{GS}$  = -4.5V,  $I_D$  = -3.7A
- Max  $r_{DS(on)} = 95m\Omega$  at  $V_{GS} = -2.5V$ ,  $I_D = -3.2A$
- Max  $r_{DS(on)} = 130 \text{m}\Omega$  at  $V_{GS} = -1.8 \text{V}$ ,  $I_D = -2.0 \text{A}$
- Max  $r_{DS(on)}$  = 195m $\Omega$  at  $V_{GS}$  = -1.5V,  $I_D$  = -1.0A
- Low profile 0.8 mm maximum in the new package MicroFET 2x2 mm
- HBM ESD protection level > 2kV typical (Note 3)
- RoHS Compliant
- Free from halogenated compounds and antimony oxides

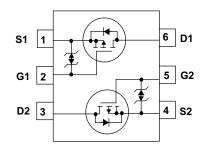


## **General Description**

This device is designed specifically as a single package solution for the battery charge switch in cellular handset and other ultra-portable applications. It features two independent P-Channel MOSFETs with low on-state resistance for minimum conduction losses. When connected in the typical common source configuration, bi-directional current flow is possible.

The MicroFET 2X2 package offers exceptional thermal performance for its physical size and is well suited to linear mode applications.





## MOSFET Maximum Ratings T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
$V_{DS}$	Drain to Source Voltage		-20	V
$V_{GS}$	Gate to Source Voltage		±8	V
	Drain Current -Continuous	(Note 1a)	-3.7	
ID	-Pulsed		-6	A
D	Power Dissipation	(Note 1a)	1.5	W
$P_{D}$		(Note 1b)	0.7	] vv
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range		-55 to +150	°C

#### **Thermal Characteristics**

$R_{\theta JA}$	Thermal Resistance for Single Operation, Junction to Ambient	(Note 1a)	86	
$R_{\theta JA}$	Thermal Resistance for Single Operation, Junction to Ambient	(Note 1b)	173	°C/W
$R_{\theta JA}$	Thermal Resistance for Dual Operation, Junction to Ambient	(Note 1c)	69	] C/VV
$R_{\theta JA}$	Thermal Resistance for Dual Operation, Junction to Ambient	(Note 1d)	151	

#### **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
023	FDMA1023PZ	MicroFET 2X2	7"	8mm	3000 units

# **Electrical Characteristics** $T_J = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	$I_D = -250 \mu A, V_{GS} = 0 V$	-20			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	$I_D = -250\mu\text{A}$ , referenced to 25°C		-11		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = -16V, \ V_{GS} = 0V$			-1	μΑ
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 8V, V_{DS} = 0V$			±10	μА

#### On Characteristics

V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = -250 \mu A$	-0.4	-0.7	-1.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250\mu A$ , referenced to 25°C		2.5		mV/°C
	$V_{GS} = -4.5V, I_D = -3.7A$		60	72		
	r <sub>DS(on)</sub> Static Drain to Source On-Resistance	$V_{GS} = -2.5V$ , $I_D = -3.2A$		75	95	
r <sub>DS(on)</sub>		$V_{GS} = -1.8V$ , $I_D = -2.0A$		100	130	mΩ
		$V_{GS} = -1.5V, I_D = -1.0A$		130	195	
		$V_{GS} = -4.5V$ , $I_D = -3.7A$ , $T_J = 125$ °C		81	91	
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = -5V, I_{D} = -3.7A$		12		S

## **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	V = 40V V = 0V	490	655	pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = -10V, V <sub>GS</sub> = 0V, f = 1MHz	100	135	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	1 111112	90	135	pF

## **Switching Characteristics**

t <sub>d(on)</sub>	Turn-On Delay Time		9	18	ns
t <sub>r</sub>	Rise Time	$V_{DD} = -10V, I_{D} = -1A$ $V_{GS} = -4.5V, R_{GEN} = 6\Omega$	12	22	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	V <sub>GS</sub> = -4.5V, R <sub>GEN</sub> = 012	64	103	ns
t <sub>f</sub>	Fall Time		37	60	ns
$Q_{g(TOT)}$	Total Gate Charge	$V_{DD} = -10V, I_D = -3.7A$	8.6	12	nC
$Q_{gs}$	Gate to Source Gate Charge	V <sub>GS</sub> = -4.5V	0.7		nC
$Q_{gd}$	Gate to Drain "Miller" Charge		2.0		nC

#### **Drain-Source Diode Characteristics**

I <sub>S</sub>	Maximum Continuous Source-Drain Diode Forward Current				-1.1	Α
$V_{SD}$	Source to Drain Diode Forward Voltage $V_{GS} = 0V$ , $I_S = -1.1A$ (Note 2)			-0.8	-1.2	V
t <sub>rr</sub>	Reverse Recovery Time	-I <sub>F</sub> = -3.7A, di/dt = 100A/μs		32	48	ns
Q <sub>rr</sub>	Reverse Recovery Charge	1F = -3.7A, αl/αt = 100A/μs		15	23	nC

#### Notes:

- 1: R<sub>0JA</sub> is determined with the device mounted on a 1 in<sup>2</sup> oz. copper pad on a 1.5 x 1.5 in. board of FR-4 material. R<sub>0JC</sub>is guaranteed by design while R<sub>0JA</sub> is determined by the user's board design.

  (a) R<sub>0JA</sub> = 86°C/W when mounted on a 1in<sup>2</sup> pad of 2 oz copper, 1.5" x 1.5" x 0.062" thick PCB. For single operation.

  - (b)  $R_{\theta JA}$  = 173°C/W when mounted on a minimum pad of 2 oz copper. For single operation.
  - (c)  $R_{\theta JA} = 69^{o}$ C/W when mounted on a 1in<sup>2</sup> pad of 2 oz copper, 1.5" x 1.5" x 0.062" thick PCB, For dual operation.
  - (d)  $R_{\theta JA}$  = 151°C/W when mounted on a minimum pad of 2 oz copper. For dual operation.



- 2: Pulse Test : Pulse Width < 300us, Duty Cycle < 2.0%
- 3: The diode connected between the gate and source serves only as protection against ESD. No gate overvoltage rating is implied.

### Typical Characteristics T<sub>J</sub> = 25°C unless otherwise noted

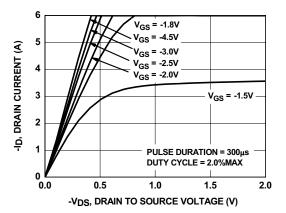


Figure 1. On Region Characteristics

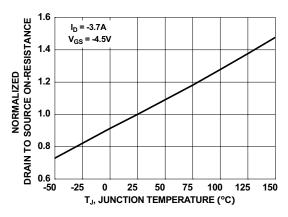


Figure 3. Normalized On-Resistance vs Junction Temperature

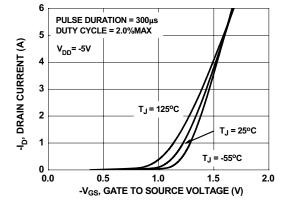


Figure 5. Transfer Characteristics

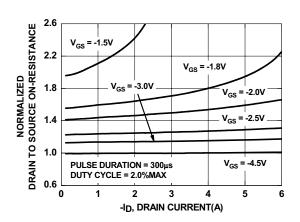


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

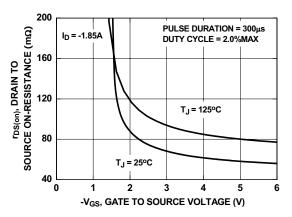


Figure 4. On-Resistance vs Gate to Source Voltage

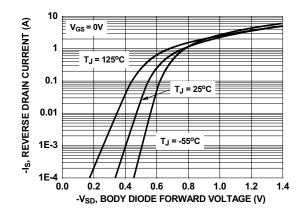


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

## Typical Characteristics T<sub>J</sub> = 25°C unless otherwise noted

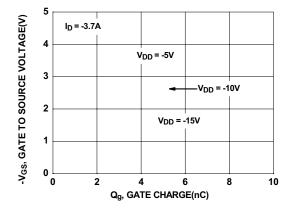


Figure 7. Gate Charge Characteristics

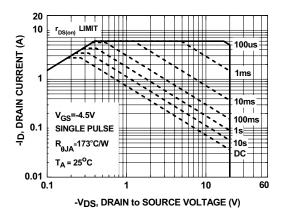


Figure 9. Forward Bias Safe Operating Area

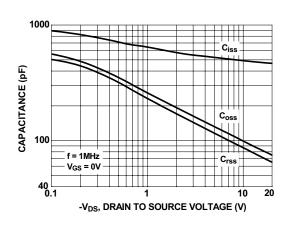


Figure 8. Capacitance Characteristics

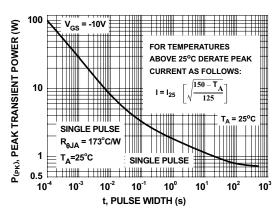


Figure 10. Single Pulse Maximum Power Dissipation

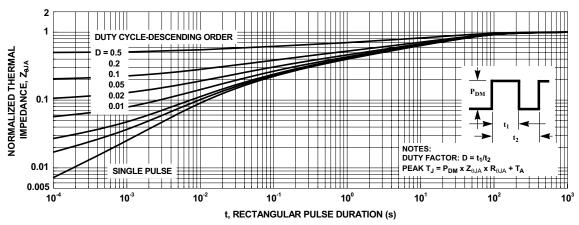
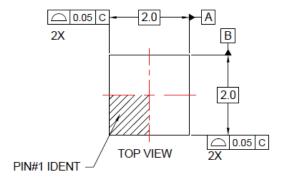
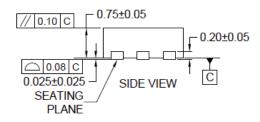
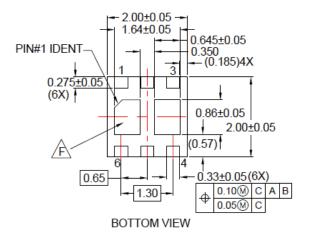


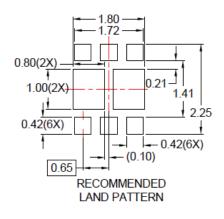
Figure 11. Transient Thermal Response Curve

## **Dimensional Outline and Pad Layout**









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